



30V Complementary Enhancement Mode MOSFET

Voltage

30 / -30V

Current

4.4 /-2.9A

Features

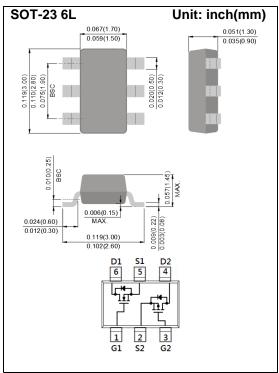
- Advanced Trench Process Technology
- Specially Designed for Switch Load, PWM Application, etc.
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

Mechanical Data

• Case: SOT-23 6L Package

• Terminals : Solderable per MIL-STD-750, Method 2026

• Approx. Weight: 0.0005 ounces, 0.014 grams



Maximum Ratings and Thermal Characteristics (T_A=25°C unless otherwise noted)

PARAMETER	SYMBOL	N-Ch LIMIT	P-Ch LIMIT	UNITS	
Drain-Source Voltage		V _{DS}	30 -30		V
Gate-Source Voltage		V _{GS}	<u>+</u> 20 <u>+</u> 20		V
Continuous Drain Current		I _D	4.4	-2.9	Α
Pulsed Drain Current ^(Note 4)		I _{DM}	17.6	-11.6	Α
5 5	T _a =25°C	_	1.25		W
Power Dissipation	Derate above 25°C	P _D	1	mW/°C	
Operating Junction and Storage Temperature Range		T _J ,T _{STG}	-55~150		°C
Typical Thermal Resistance - Junction to Ambient ^(Note 3)		ReJA	100		°C/W





N-Channel Electrical Characteristics (T_A=25°C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V, I _D =250uA	30	-	-	V
Gate Threshold Voltage	$V_{GS(th)}$	V _{DS} =V _{GS} , I _D =250uA	1.0	1.37	2.1	V
Drain-Source On-State Resistance	R _{DS(on)}	V _{GS} =10V, I _D =4.4A	-	36	48	mΩ
		V _{GS} =4.5V, I _D =2.8A	-	52	70	
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =30V, V _{GS} =0V	-	-	1	uA
Gate-Source Leakage Current	I _{GSS}	V _{GS} = <u>+</u> 20V, V _{DS} =0V	-	-	<u>+</u> 100	nA
Dynamic ^(Note 5)			•			
Total Gate Charge	Qg	V _{DS} =15V, I _D =4.4A, V _{GS} =10V ^(Note 1,2)	-	5.8	-	nC
Gate-Source Charge	Q_{gs}		-	1	-	
Gate-Drain Charge	Q_{gd}		-	1	-	
Input Capacitance	Ciss	V _{DS} =15V, V _{GS} =0V, f=1.0MHZ	-	235	-	pF
Output Capacitance	Coss		-	36	-	
Reverse Transfer Capacitance	Crss		-	24	-	
Turn-On Delay Time	td _(on)	$V_{DD}{=}15V,\ I_{D}{=}4.4A,$ $V_{GS}{=}10V,$ $R_{G}{=}6\Omega^{(Note\ 1,2)}$	-	3	-	ns
Turn-On Rise Time	tr		-	39	-	
Turn-Off Delay Time	td _(off)		-	23	-	
Turn-Off Fall Time	tf		-	28	-	
Drain-Source Diode						
Maximum Continuous Drain-Source	,		-	-	1.5	А
Diode Forward Current	Is					
Diode Forward Voltage	V _{SD}	I _S =1.0A, V _{GS} =0V	-	0.8	1.2	V

NOTES:

- 1. Pulse width<300us, Duty cycle<2%
- 2. Essentially independent of operating temperature typical characteristics.
- 3. ROJA is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins mounted on a 1 inch FR-4 with 2oz. square pad of copper.
- 4. The maximum current rating is package limited.
- 5. Guaranteed by design, not subject to production testing





P-Channel Electrical Characteristics (T_A=25°C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V, I _D =-250uA	-30	-	-	V
Gate Threshold Voltage	$V_{GS(th)}$	V _{DS} =V _{GS} , I _D =-250uA	-1	-1.3	-2.1	V
Drain-Source On-State Resistance	R _{DS(on)}	V _{GS} =-10V, I _D =-2.9A	-	94	110	mΩ
		V _{GS} =-4.5V, I _D =-1.9A	-	120	150	
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =-30V, V _{GS} =0V	-	-	-1	uA
Gate-Source Leakage Current	I _{GSS}	V _{GS} = <u>+</u> 20V, V _{DS} =0V	-	-	<u>+</u> 100	nA
Dynamic ^(Note 5)						
Total Gate Charge	Q_g	V _{DS} =-15V, I _D =-2.9A, V _{GS} =-10V ^(Note 1,2)	-	9.8	-	nC
Gate-Source Charge	Q_gs		-	1.5	-	
Gate-Drain Charge	Q_gd		-	2.2	-	
Input Capacitance	Ciss	V _{DS} =-15V, V _{GS} =0V, f=1.0MHZ	-	396	-	pF
Output Capacitance	Coss		-	47	-	
Reverse Transfer Capacitance	Crss		-	36	-	
Turn-On Delay Time	td _(on)	V_{DD} =-15V, I_{D} =-2.9A, V_{GS} =-10V, R_{G} =6 $\Omega^{(Note\ 1,2)}$	-	5	-	
Turn-On Rise Time	tr		-	30	-	
Turn-Off Delay Time	td _(off)		-	25	-	ns
Turn-Off Fall Time	tf		-	8	-	
Drain-Source Diode						
Maximum Continuous Drain-Source					4.5	
Diode Forward Current	Is		-		-1.5	Α
Diode Forward Voltage	V _{SD}	I _S =-1.0A, V _G S=0V	-	-0.85	-1.2	V

NOTES:

- 1. Pulse width<300us, Duty cycle<2%
- 2. Essentially independent of operating temperature typical characteristics.
- 3. ROJA is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins mounted on a 1 inch FR-4 with 2oz. square pad of copper.
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N-Channel TYPICAL CHARACTERISTIC CURVES

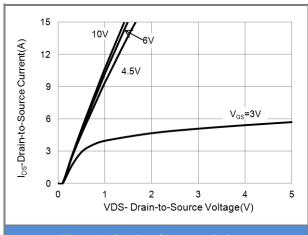


Fig.1 On-Region Characteristics

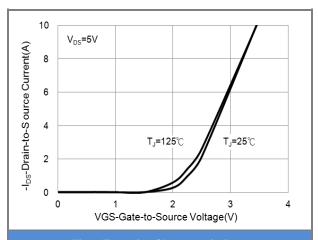


Fig.2 Transfer Characteristics

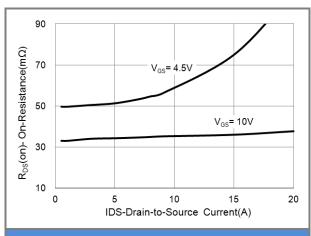


Fig.3 On-Resistance vs. Drain Current

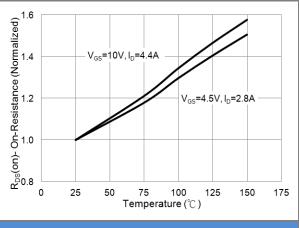
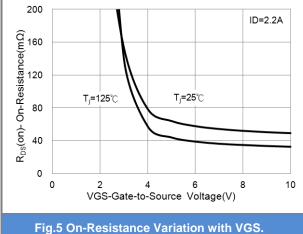


Fig.4 On-Resistance vs. Junction temperature



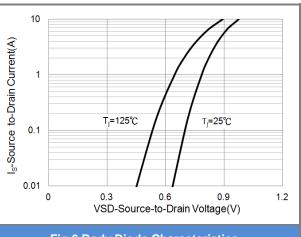


Fig.6 Body Diode Characteristics





N-Channel TYPICAL CHARACTERISTIC CURVES

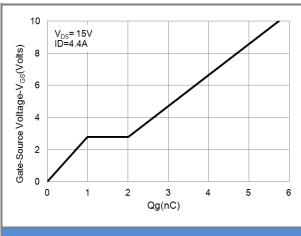


Fig.7 Gate-Charge Characteristics

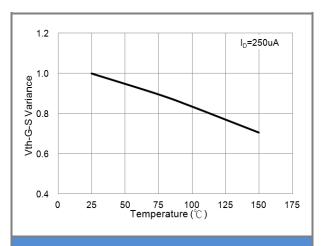


Fig.8 Threshold Voltage Variation with Temperature.

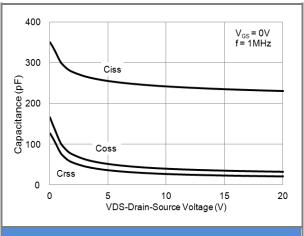


Fig.9 Capacitance vs. Drain-Source Voltage.





P-Channel TYPICAL CHARACTERISTIC CURVES

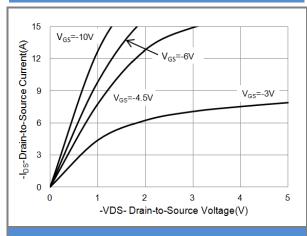


Fig.1 On-Region Characteristics

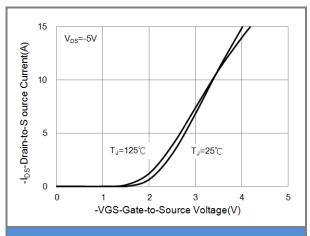


Fig.2 Transfer Characteristics

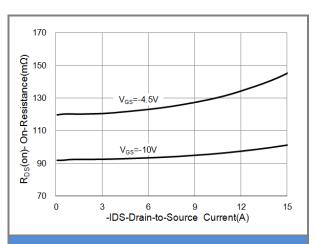


Fig.3 On-Resistance vs. Drain Current

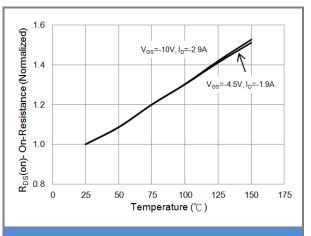


Fig.4 On-Resistance vs. Junction temperature

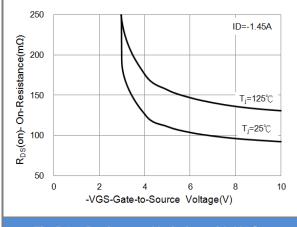
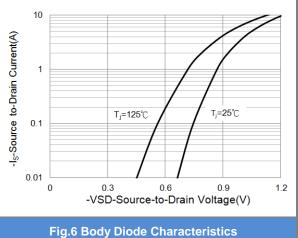


Fig.5 On-Resistance Variation with VGS.







P-Channel TYPICAL CHARACTERISTIC CURVES

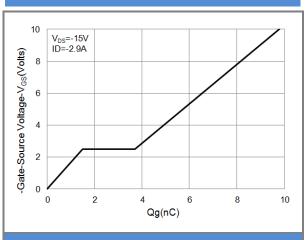


Fig.7 Gate-Charge Characteristics

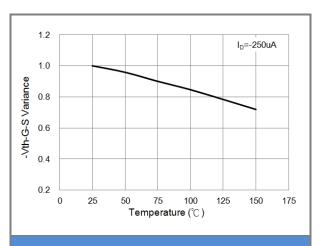


Fig.8 Threshold Voltage Variation with Temperature.

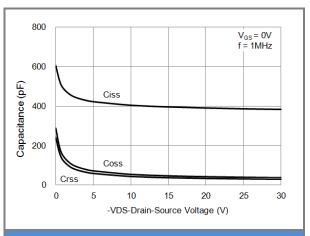


Fig.9 Threshold Voltage Variation with Temperature.

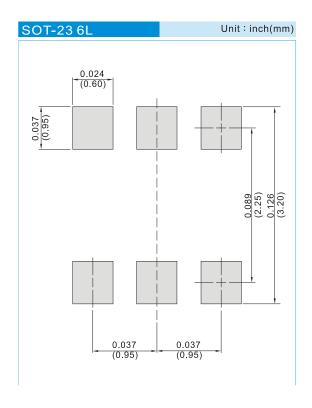




PART NO. PACKING CODE VERSION

Part No. Packing Code	Package Type	Packing Type	Marking	Version
PJS6603_S1_00001	SOT-23 6L	3K pcs / 7" reel	SC3	Halogen free RoHS compliant
PJS6603_S2_00001	SOT-23 6L	10K pcs / 13" reel	SC3	Halogen free RoHS compliant

MOUNTING PAD LAYOUT







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